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Bonding and stability of donor ligand-supported heavier analogues of cyanogen halides (L')PSi(X)(L)†

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Fluoro- and chloro-phosphasilynes [X–Si≡P (X = F, Cl)] belong to a class of elusive chemical species which are expected to have Si≡P multiple bonds. Theoretical investigations of the bonding and stability of the corresponding Lewis base-stabilized species (L')PSi(X)(L) [L' = cAAC^{Me} (cyclic alkyl(amino) carbene); L = cAAC^{Me}, NHC^{Me} (N-heterocyclic carbene), PMe₃, aAAC (acyclic alkyl(amino) carbene); X = Cl, F] have been studied using the energy decomposition analysis-natural orbitals for chemical valence (EDA-NOCV) method. The variation of the ligands (L) on the Si-atom leads to different bonding scenarios depending on their σ-donation and π-back acceptance properties. The ligands with higher lying HOMOs prefer profoundly different bonding scenarios than the ligands with lower lying HOMOs. The type of halogen (Cl or F) on the Si-atom was also found to have a significant influence on the overall bonding scenario. The reasonably higher value and endergonic nature of the dissociation energies along with the appreciable HOMO–LUMO energy gap may corroborate to the synthetic viability of the homo and heteroleptic ligand-stabilized elusive PSi(Cl/F) species in the laboratory.

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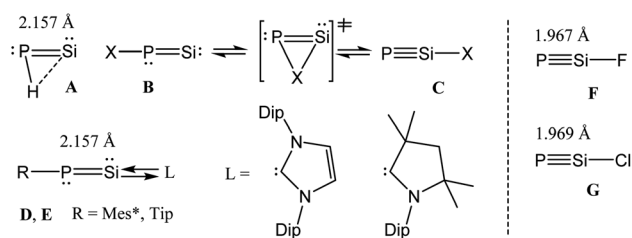
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Introduction

Cyanogen halides [N≡C–X; X = halogen = F, Cl] are stable volatile compounds, often utilized in the laboratory for organic synthesis.¹ The N≡C bond in cyanogen halides is highly stable due to the efficient overlap of the 2s and 2p orbitals of the N and C atoms. In contrast, the P≡Si bond in the heavier analogues of cyanogen halide [P≡Si–X; X = F, Cl] would involve the participation of significantly more diffused 3s and 3p orbitals with internal nodes within each type of orbital, leading to a huge deviation from the compact overlap of these orbitals.² The P≡Si bond is thus expected to be significantly weaker when compared with the N≡C bond. Although, the chemistry of low coordinate silicon and phosphorus compounds is still in its infancy when compared to that of the lighter analogues containing carbon and nitrogen; molecules containing the exotic Si=P moiety³ have received significant attention over the years. As an example, ^tBu–C≡P is kinetically stable and was isolated about four decades ago,⁴ but the analogous phosphasilynes (R–Si≡P) are still not known. On the other hand, half a decade ago phosphasilylenylidenes, Si=P–R, had been stabilized by strong σ-donation from NHC [NHC → Si=P–R; NHC = N-heterocyclic carbene].⁵ Switching the ligand field from NHC to cAAC

resulted in the isolation of the cAAC-stabilized dimer in the solid state (cAAC → Si–P–R)₂ [cAAC = cyclic alkyl(amino) carbene]. However, NMR studies showed that the monomeric species cAAC → Si=P–R is stable in THF solution nearly for a day.⁶ The phosphasilylenylidenes (Si=P–R) and phosphasilynes (R–Si≡P, R = X) are isomers of each other.^{7,8} Early theoretical works showed that the phosphasilynes (C) are more stable than the phosphasilylenylidenes (B), when R = electron withdrawing group, e.g., R = F. The presence of electropositive R groups/atoms stabilize B (Scheme 1).^{7,8} Phosphasilylenylidenes (D) were stabilized by NHC carbene, when R = 2,4,6-triisopropylphenyl.⁵ The cAAC analogue (E) was only characterized in solution (Scheme 1).⁶ Though it has been predicted that X–Si≡P compounds with electronegative substituents will be more stable than Si=P–X, till now there is no synthetic report on stable and isolable X–Si≡P (phosphasilyne) (F, G) (Scheme 1). Such species are not even characterized by matrix isolation



Scheme 1 Phosphasilylenylidenes (A–B, D–E) and phosphasilyne (C, F, G).

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method. However, there is a report on theoretical investigation of very bulky ligand (Tbt = 2,4,6-tris[bis(trimethylsilyl)methyl]phenyl) shielded R-Si≡P-R cation.^{8a}

Ph₃P, NHC, cAAC and aAAC [acyclic alkyl(amino) carbene] are often utilized as donor ligands for the stabilization of exotic species, transient species, small clusters, and bare atoms through coordination.^{9–11} Triphenylphosphine (Ph₃P) stabilized divalent carbon compound, C(PPh₃)₂ has been synthesized in 1961 by Ramirez *et al.*¹² The bonding analysis of this compound by Frenking *et al.*¹³ in 2006 showed the formation two Ph₃P→C dative σ-bonds and Ph₃P←C π-bonds, leading to the accumulations of two lone pairs of electrons on the central C-atom. The notation of arrow for a dative bond was first used by Sidgwick in the 1920s^{14a} and it was implemented for divalent carbon(0) compounds, L→C←L as suggested by Varshavskii in 1980.^{14b,c}

Herein, we report the theoretical investigation on bonding and stability of donor ligand-stabilized phosphasilyne (**F**, **G**) with the general formula (L')PSi(X)(L) [L' = cAAC^{Me}; L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC; X = Cl, F] (**n-Cl**, **n-F**; **n** = 1 (cAAC^{Me}), 2 (NHC^{Me}), 3 (aAAC), 4 (aAAC)). Additionally, the central PSi-X molecular unit containing one L ligand on either of P or Si atoms have been theoretically studied and the computed results have been compared and discussed.

Computational methods

Geometry optimizations and vibrational frequencies calculations of cAAC-PSi(Cl)-L (**1-Cl** to **4-Cl**) and cAAC-PSi(F)-L (**1-F** to **4-F**) with L = cAAC^{Me} (**1-Cl**, **1-F**), NHC^{Me} (**2-Cl**, **2-F**), PMe₃ (**3-Cl**, **3-F**) and L = aAAC (**4-Cl**, **4-F**) in singlet and triplet electronic states have been carried out at the BP86-D3(BJ)/Def2-TZVPP level¹⁵ in gas phase. The absence of imaginary frequencies assures the minima on potential energy surface. All the calculations have been performed using gaussian 16 program package.¹⁶ Natural bond orbital (NBO)¹⁷ analysis have been performed using NBO 6.0¹⁸ program to evaluate the partial charges, Wiberg bond indices (WBI)¹⁹ and natural bond orbitals. The nature of bonds in cAAC-PSi(X)-L (X = Cl, F) were analyzed by energy decomposition analysis (EDA),²⁰ coupled with natural orbital for chemical valence (NOCV)²¹ using ADF 2018.105 program package.²² EDA-NOCV calculations were carried out at the BP86-D3(BJ)/TZ2P²³ level using the geometries optimized at BP86-D3(BJ)/def2-TZVPP level. EDA-NOCV method involves the decomposition of the intrinsic interaction energy (ΔE_{int}) between the two fragments into four energy components as follows:

$$\Delta E_{\text{int}} = \Delta E_{\text{elstat}} + \Delta E_{\text{Pauli}} + \Delta E_{\text{orb}} + \Delta E_{\text{disp}} \quad (1)$$

The electrostatic, ΔE_{elstat} term is originated from the quasi-classical electrostatic interaction between the unperturbed charge distributions of the prepared fragments. The Pauli repulsion, ΔE_{Pauli} is the energy change associated with the transformation from the superposition of the unperturbed electron densities of the isolated fragments to the wavefunction, which properly obeys the Pauli principle through explicit antisymmetrization and renormalization of the production of the

wavefunction. Dispersion interaction, ΔE_{disp} is also obtained as we used D3(BJ). The orbital term, ΔE_{orb} comes from the mixing of orbitals, charge transfer and polarization between the isolated fragments. This can be further divided into contributions from each irreducible representation of the point group of the interacting system as follows:

$$\Delta E_{\text{orb}} = \sum_r \Delta E_r \quad (2)$$

The combined EDA-NOCV method is able to partition the total orbital interactions into pairwise contributions of the orbital interactions, which is important in providing a complete picture of the bonding. The charge deformation, $\Delta \rho_k(r)$ which comes from the mixing of the orbital pairs, $\psi_k(r)$ and $\psi_{-k}(r)$ of the interacting fragments, gives the magnitude and the shape of the charge flow due to the orbital interactions (eqn (3)), and the associated orbital energy, ΔE_{orb} presents the amount of orbital energy coming from such interaction (eqn (4)).

$$\Delta \rho_{\text{orb}}(r) = \sum_k \Delta \rho_k(r) = \sum_{k=1}^{N/2} [\nu_k - \psi_{-k}^2(r) + \psi_k^2(r)] \quad (3)$$

$$\Delta E_{\text{orb}} = \sum_k \Delta E_{\text{orb}}^k = \sum_k \nu_k \left[-F_{-k,-k}^{\text{TS}} + F_{k,k}^{\text{TS}} \right] \quad (4)$$

Readers are further referred to the recent review articles to know more about the EDA-NOCV method and its applications.²⁴

Results and discussion

We initiated our studies with the geometry optimization of **F** and **G** and all the ligands (aAAC, cAAC^{Me}, NHC^{Me}, PMe₃). The energy gap between HOMO and LUMO increases in the order of aAAC > cAAC^{Me} > NHC^{Me} > PMe₃ (Fig. S14†). The energy of HOMO also follows the same order with highest lying for aAAC and lowest lying for PMe₃. **F** and **G** are singlet species and have a linear geometry with a Si≡P bond.

The optimized geometries of four cAAC-PSi(Cl)-L (**1-Cl** to **4-Cl**) and four cAAC-PSi(F)-L compounds (**1-F** to **4-F**) with L = cAAC^{Me} (**1-Cl**, **1-F**), NHC^{Me} (**2-Cl**, **2-F**), PMe₃ (**3-Cl**, **3-F**) and L = aAAC (**4-Cl**, **4-F**) in their electronic singlet states are shown in Fig. 1. The choice of ligands is based on their σ-donating and π-accepting ability and their effect in stabilizing the group 14 and 15 elements. The π-accepting ability of ligands increases in the order of PMe₃ < NHC < aAAC < cAAC with cAAC being a very good σ donor as well as better π-acceptor compared to NHC which is a good σ-donor, but a poor π-acceptor followed by PMe₃ which is only a σ-donor. Since (cAAC)P⁻ anion is now readily accessible in the laboratory, cAAC^{Me} (L') has been kept fixed at P-atom.²⁵ The singlet states of all the complexes are found to be lower in energy than the corresponding triplet states by 21.2 to 40.7 kcal mol⁻¹ (Fig. S1†). Theoretical calculations at BP86/Def2-TZVPP level of theory suggests that the both Si bonded ligands and P bonded cAAC^{Me} ligand in compounds **1-Cl**, **2-Cl**, **4-Cl** and **1-F**, **2-F**, **4-F** are slightly perpendicular to each other with respect to C-P-Si and P-Si-C

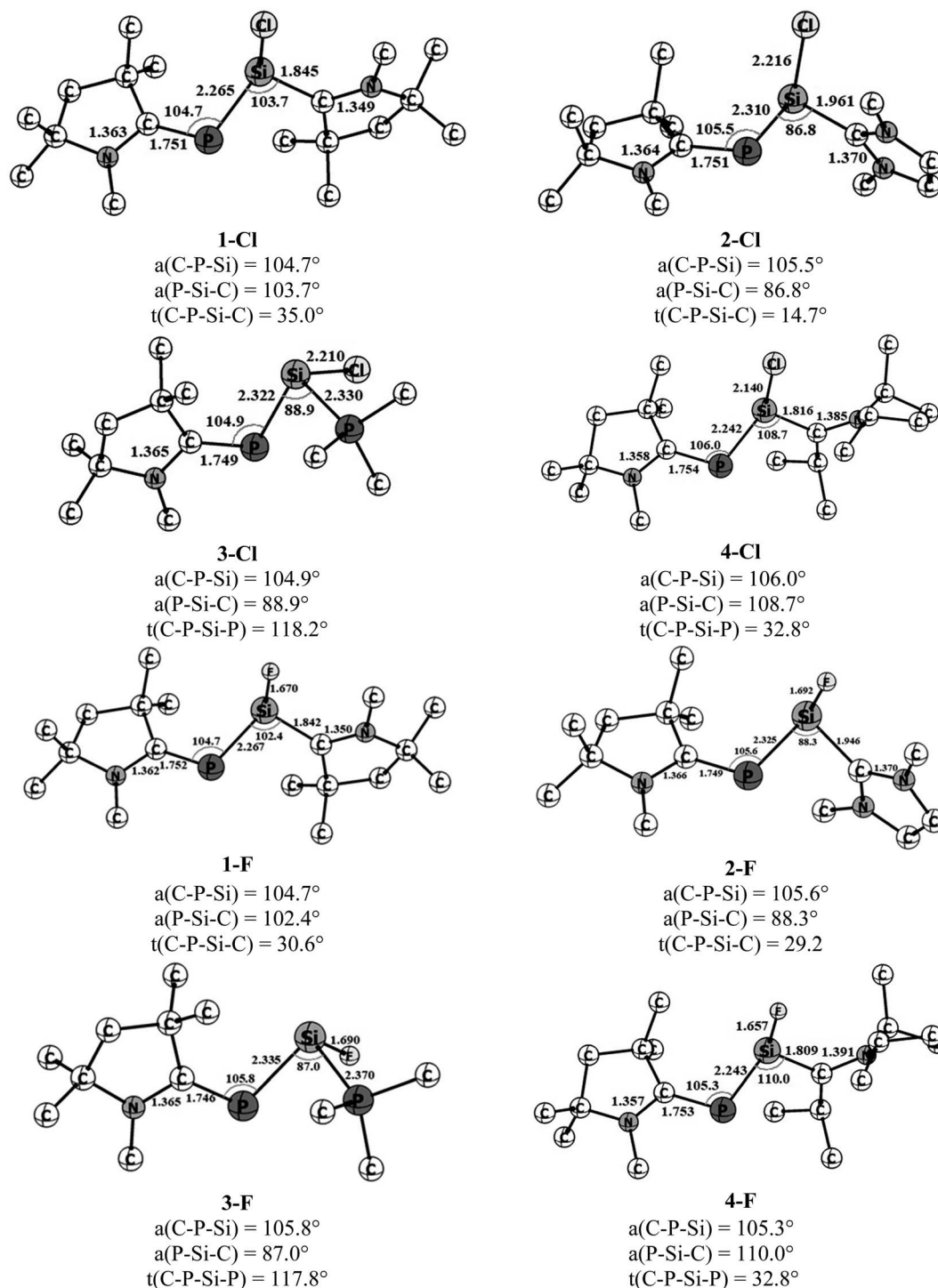


Fig. 1 Optimized geometries of cAAC-PSi(Cl/F)-L, 1-Cl to 4-Cl and 1-F to 4-F in ground state singlet with L = cAAC^{Me} (1-Cl, 1-F), NHC^{Me} (2-Cl, 2-F), PMe₃ (3-Cl, 3-F) and aAAC (4-Cl, 4-F) at BP86-D3(BJ)/def2-TZVPP level.

planes which has reflected through C-P-Si-C torsion angles of 14.7–35° (Fig. 1). It is noteworthy to mention that the C-P-Si-C torsion angle significantly increases from 14.7° in 2-Cl to 29° in 2-F. This suggests different orbital interactions between terminal cAAC^{Me}/NHC^{Me} ligands and central P-Si moieties of these two compounds (2-Cl, 2-F). The C-P-Si-P torsion angles of 117.8–118.2° in 3-Cl and 3-F (L = PMe₃) indicate deviation from

planarity. The C_{cAAC}-P bond lengths of 1.746–1.754 Å in the present compounds are very close to those of the reported values, 1.740(2) and 1.739(2) for (cAAC)P-Si(cAAC)-P(cAAC).²⁶ The Si-C_L bond length varies with varying the ligand (L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC) and also with substitution (Cl or F) on Si-atom. In Cl substituted compounds, the Si-C bond length varies from 1.816 Å in 4-Cl (L = aAAC), 1.842 Å in 1-Cl (L

Table 1 NBO results of the complexes cAAC–P–Si(Cl)–L (L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC) (1-Cl to 4-Cl) at the BP86/def2-TZVPP level of theory. Occupation number (ON), polarization and hybridization of the C_{cAAC}–P, P–Si and Si–C_L bonds and partial charges *q*

Complex	Bond	ON	Polarization and hybridization (%)	WBI	<i>q</i>		
					P	Si	
1-Cl	C _{cAAC} –P	1.91	C: 39.8 s(0.0), p(99.8)	P: 60.2 s(0.0), p(99.5)	1.49	–0.08	0.65
		1.97	C: 65.2 s(38.6), p(61.1)	P: 34.8 s(18.8), p(80.3)			
	P–Si	1.91	P: 57.7 s(14.4), p(84.7)	Si: 42.3 s(33.5), p(65.9)	0.94		
		1.64	Si: 42.1 s(43.9), p(55.5)	C: 57.9 s(24.6), p(68.8)			
2-Cl	C _{cAAC} –P	1.53	Si: 61.0 s(3.10), p(96.6)	C: 39.0 s(16.2), p(73.5)	1.49	–0.14	0.39
		1.90	C: 40.1 s(0.0), p(99.8)	P: 59.9 s(0.0), p(99.6)			
	P–Si	1.97	C: 65.1 s(38.8), p(60.9)	P: 34.9 s(20.1), p(79.1)	0.93		
		1.88	P: 62.5% s(15.1), p(84.3)	Si: 37.5% s(11.7), p(87.3)			
3-Cl	C _{cAAC} –P	1.94	Si: 22.9 s(10.6), p(88.2)	C: 77.1 s(43.1), p(56.8)	0.76		
		1.97	C: 65.2% s(38.8), p(60.8)	P: 34.8 s(20.1), p(79.1)			
	P–Si	1.91	C: 40.9 s(0.1), p(99.8)	P: 59.1 s(0.0), p(99.5)	1.50	–0.14	0.27
		1.91	P: 61.9 s(14.4), p(85.0)	Si: 38.1 s(10.9), p(88.0)			
4-Cl	C _{cAAC} –P	1.94	Si: 26.6 s(7.5), p(91.5)	P: 73.4 s(30.1), p(69.6)	0.77		
		1.96	C: 65.1% s(38.3), p(61.7)	P: 34.9 s(19.5), p(80.5)			
	P–Si	1.90	P: 57.9 s(14.7), p(84.3), d(1)	Si: 42.1 s(34.3), p(65.7)	1.46	–0.08	0.79
		1.90	Si: 34.3 s(44.9), p(55.1)	C: 65.7 s(28.1), p(71.9)			
		1.84	Si: 41.5 s(2.5), p(97.5)	C: 58.5 s(10.7), p(89.3)	1.23		

= cAAC^{Me}),²⁷ 1.961 Å in **2-Cl** (L = NHC^{Me}),²⁸ suggesting significant π -backdonation (Si \rightarrow C_{cAAC}) as expected and observed in (cAAC)₂Si₂Cl₂ (1.823(3)/1.826(3) Å) containing a partial Si–C_{cAAC} double bond (Si \leftarrow C_{cAAC} and, Si \rightarrow C_{cAAC}).²⁷ The Si–P bond distance is 2.330 Å in **3-Cl** (L = PMe₃), which is slightly shorter than that of H₂Si \leftarrow PH₃ (2.39 Å) and longer than that of electron sharing covalent Si–P single bond distance in H₃Si–PH₂ (2.258 Å).^{8c} On replacement of Cl with F on Si, the Si–C_L bond length almost remains same in **1-F** (1.842 Å),²⁷ while, it slightly decreases in **2-F** (1.946 Å), **4-F** (1.809 Å) and the Si–P_{PMe₃} bond length slightly increases in **3-F** (Si–P 2.370 Å). The Si–C_L bond lengths are comparable to the reported Si–C_{carbene} bond lengths of 1.985 Å and 1.939 Å in (NHC)SiCl₂²⁸ and (NHC)₂Si₂Cl₂,²⁹ respectively. The π -back acceptance property of NHC is negligible in these compounds.^{28,29} The calculated (cAAC)P–Si bond distance ranges from 2.265 to 2.335 Å, depending on the ligand coordinated to Si with 2.265–2.267 Å (P–Si–cAAC), 2.310–2.325 Å (P–Si–NHC), 2.322–2.335 Å (P–Si–PMe₃) and 2.243 Å (P–Si–aAAC), which are lower than P=Si bond lengths (2.125 Å)³⁰ and comparable to P–Si single bond distance (2.29 Å)³¹ though differ by substituents. All the compounds possess rather acute \angle C_{cAAC}–P–Si (\sim 105–106°) and \angle P–Si–C_L (86.8–110.0°) bond angles. The \angle P–Si–C_L bond angles varies in the order of L = NHC^{Me} < PMe₃ < cAAC^{Me} < aAAC for chloro-substituted Si (Si–Cl) and the order changes for fluoro-substituted Si (Si–F) as L = PMe₃ < NHC^{Me} < cAAC^{Me} < aAAC. The steric crowding of ligand L bonded to Si influences the \angle P–Si–C_L bond angles. The larger \angle P–Si–C_L bond angles 108.7–110° in **4-Cl** and **4-F** is due to higher steric crowding in aAAC ligands followed by cAAC ligands in **1-Cl** and **1-F** (102.4–103.7°). While, the lower steric crowding in NHC and PMe₃ ligands resulted in acute bond angles (86.8–88.9°). The \angle C–C–N bond angle is slightly higher in aAAC (114.1–114.5°) (**4-Cl**, **4-F**) than that in cAAC (107.0–107.4°) ligand in **1-Cl** and **1-F**. This increase in \angle C–C–N bond

angle might influence the bonding in the corresponding compounds.

We have also evaluated the thermochemical stability with respect to dissociation, (cAAC)P–Si(X)(L) \rightarrow (cAAC) + P–Si(X) + L (X = Cl, F; L = cAAC^{Me}, NHC^{Me}, PMe₃ and aAAC). The bond dissociation energy (BDE) values were calculated at 0 K and change in Gibbs free energy at 298 K (ΔG^{298}). The dissociation energy (*D_e*) values of all eight complexes varies with L in the order of PMe₃ < NHC^{Me} < aAAC < cAAC^{Me}. The dissociation is found to be the highest (127.4–129.0 kcal mol^{–1}) in case of cAAC–PSi(Cl/F)–cAAC, **1-Cl**, **1-F**, followed by cAAC–PSi(Cl/F)–aAAC, **4-Cl**, **4-F** (120.5–122.6 kcal mol^{–1}), cAAC–PSi(Cl/F)–NHC, **2-Cl**, **2-F** (114–115.35 kcal mol^{–1}) and the lowest in case of cAAC–PSi(Cl/F)–PMe₃, **3-Cl**, **3-F** (100–102.2 kcal mol^{–1}). The *D_e* of fluoro-substituted compounds are found to be higher compared to their chloro-substituted counterparts with the exception of cAAC–PSi(Cl/F)–PMe₃, where cAAC–PSi(Cl)–PMe₃ have slightly higher *D_e* compared to cAAC–PSi(F)–PMe₃. The dissociation is endergonic in nature at room temperature and the endergonicity follows the same trend of *D_e* in the order of L with L = PMe₃ (ΔG^{298} = 86.3–87 kcal mol^{–1}) < NHC^{Me} (ΔG^{298} = 100.7–101.7 kcal mol^{–1}) < aAAC (ΔG^{298} = 104.4–106.4 kcal mol^{–1}) < cAAC^{Me} (ΔG^{298} = 111.5–113.7 kcal mol^{–1}). The reasonably high *D_e* and endergonic nature of dissociation indicates the stability of the compounds. The HOMO–LUMO energy gap (Δ_{H-L}) determines the electronic stability and reactivity of a molecule in its ground state. High Δ_{H-L} denotes higher electronic stability and less reactivity. The present compounds under study showed good HOMO–LUMO energy gap in the range of 46–60 kcal mol^{–1}. We have found that the HOMO–LUMO energy gap varies with L in the order of cAAC^{Me} < aAAC < NHC^{Me} < PMe₃ (Table S1†).

We have utilized NBO method to understand the electronic structure, charge distribution and the nature of bonding. The

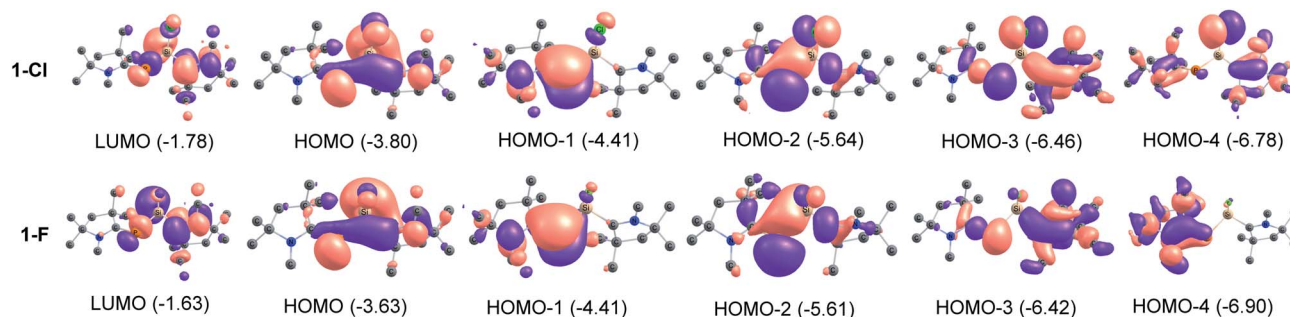


Fig. 2 Molecular orbitals of 1-Cl and 1-F at BP86-D3(BJ)/def2-TZVPP level.

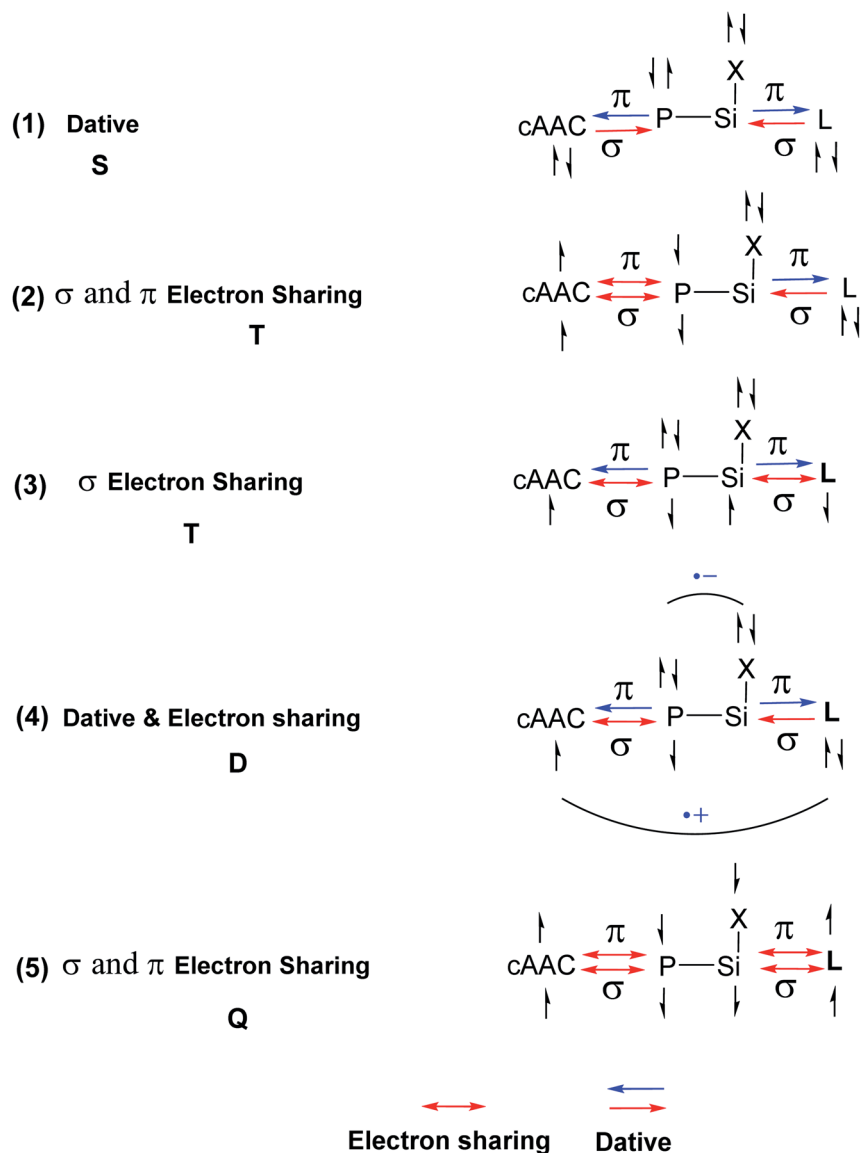
results in Table 1 identifies the $C_{\text{CAAC}}=\text{P}$ bonds (σ and π). While, the σ bonds are polarized towards the C-atom of cAAC^{Me} ligand ($\text{C}\rightarrow\text{P}$), the π bonds ($\text{C}\leftarrow\text{P}$) are polarized towards P atom. The $\text{cAAC}=\text{P}$ bond order of 1.23–1.50 supports the above description of donor–acceptor type. The Si–C/ P_{L} bond order of 0.76–0.77 in 2-Cl and 3-Cl suggests that Si–C/ P_{L} bond is a single bond which is polarized toward the ligand (L). The bond order of 1.14–1.23 and σ and π bond occupancies in 1-Cl and 4-Cl suggests a Si– C_{CAAC} weak π contribution ($\text{Si}\leftarrow C_{\text{CAAC}}$). NBO analysis shows that the P–Si bond is predominantly single bond in all compounds. The bond order of 0.93–0.97 testifies a P–Si single bond. MO analysis shows that HOMO is essentially MO containing lone pairs of P and Si atoms (Fig. 2). The HOMO–1 is clearly the $\text{cAAC}^{\text{Me}}=\text{P}$ π -bonding MO with little contribution towards cAAC. HOMO–2 represents the lone pair on P and some overlap of lobes on Si with adjacent atoms. HOMO–3 is a σ type orbital on cAAC^{Me} , extending towards P-atom of $\text{cAAC}=\text{P}$ unit and ligand specific interactions like C–N interaction, when $\text{L} = \text{cAAC}^{\text{Me}}$ and delocalization of electrons, when $\text{L} = \text{NHC}^{\text{Me}}$. HOMO–4 represents Si–Cl orbital with π type interaction. The MOs of fluoro-substituted compounds (1-F to 4-F) (Table S2[†]) are similar to that of the chloro-substituted ones (1-Cl to 4-Cl), but it is to be noted that the orbitals on F are too small to extend interaction towards the lobes of Si which is present in HOMO–4 of chloro-substituted compounds (Fig. 2, S2 and S3[†]).

The NBO results, however cannot distinguish the dative or electron sharing interactions and thus not the true nature of the bond. NBO also cannot produce the clear picture of electronic structure of each fragment and the corresponding bonding between them. In this respect, energy decomposition analysis–natural orbital with chemical valence (EDA–NOCV) approach is useful to give a detailed insight into the nature of the chemical bonds of cAAC–PSi(Cl/F)–L ($\text{L} = \text{cAAC}^{\text{Me}}$, NHC^{Me} , PMe_3 , aAAC) (1-Cl to 4-Cl and 1-F to 4-F) by its ability to provide the best bonding model to represent the overall bonding situation in the molecule. The bonding possibility with lowest ΔE_{orb} is considered as the best bonding representation, since it needs the least change in the electronic charge of the fragments to make the electronic structure of the molecule.³²

In the present study, the best bonding description of cAAC–PSi(X)–L molecules ($\text{X} = \text{Cl}$ for 1-Cl to 4-Cl and $\text{X} = \text{F}$ for 1-F to 4-F) is portrayed by considering five different bonding

possibilities (Scheme 2) by varying the charge and electronic states of the interacting fragments $[(\text{cAAC})(\text{L})]$ and P–Si(X) , viz., (1) neutral $[(\text{cAAC})\text{L}]$ and P–Si(X) fragments in their electronic singlet state forming dative bonds, (2) neutral $[(\text{cAAC})\text{L}]$ and P–Si(X) fragments in their electronic triplet state leading to the formation of σ and π electron sharing bonds and other σ and π dative bonds, (3) neutral $[(\text{cAAC})(\text{L})]$ and P–Si(X) fragments in their electronic triplet state leading to the formation σ electron sharing bonds and π dative bonds, (4) singly charged $[(\text{cAAC})\text{L}]^+$ and $[\text{P–Si(X)}]^-$ fragments in electronic doublet state, which would interact to form both electron sharing and dative bonds and (5) neutral $[(\text{cAAC})(\text{L})]$ and P–Si(X) fragments in their electronic quintet state leading to the formation four electron sharing bonds. Energy decomposition analysis (EDA) coupled with natural orbital for chemical valence (NOCV) results from Table 2 shows that for carbene containing compounds 1-Cl, 2-Cl and 4-Cl, the fragmentation scheme involving singly charged $[(\text{cAAC})\text{L}]^+$ and $[\text{P–Si(X)}]^-$ fragments in electronic doublet state (Scheme 2; (4)) forming both electron sharing and dative bonds gives the smallest ΔE_{orb} and hence fits the best bonding scenario. In fact, for 2-Cl ($\text{L} = \text{NHC}$) bonding possibility (2) forming σ and π electron sharing bonds also have comparable ΔE_{orb} value with the best bonding possibility (4), indicating that the σ and π electron sharing bonding model might also be valid in describing the bonding. Similarly, for 4-Cl ($\text{L} = \text{aAAC}$) the bonding model can also be expressed in terms of all electron sharing bonds with neutral interacting fragments in quintet states (5). On the other hand, for complex 3-Cl ($\text{L} = \text{PMe}_3$) the best bonding description of cAAC–PSi(Cl)–L bonds comes from the interaction of neutral $[(\text{cAAC})\text{L}]$ and P–Si(Cl/F) fragments in triplet electronic states (Scheme 2; (2)) with cAAC forming both electron sharing σ and π bonds with P-atom of P–Si(Cl) unit and PMe_3 forming dative bonds with Si-atom.

The results of EDA–NOCV for the most favorable bonding model are given in Table 3. In compounds 1-Cl, 2-Cl and 4-Cl ($\text{L} = \text{carbene}$), the cAAC–PSi(Cl)–L ($\text{L} = \text{cAAC}^{\text{Me}}$ and NHC^{Me}) bonds are 50.3 to 51.3% electrostatic in nature and the remaining 45.8 to 46.9% comes from covalent interactions and 2.6–2.9% from dispersion contribution. Further breakdown of ΔE_{orb} into pairwise contributions gives more detailed information about the nature of bonding. There are five relevant orbital contributions, $\Delta E_{\text{orb}(1)}-\Delta E_{\text{orb}(5)}$ and the nature of orbital terms and corresponding fragment molecular orbitals can be understood



Scheme 2 Bonding possibilities of cAAC–P–Si(X)–L bonds of cAAC–P–Si(X)–L (L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC; X = Cl, F) 1-Cl to 4-Cl and 1-F to 4-F.

with the help of associated deformation densities, $\Delta\rho_n$ (Fig. 3–5 and S4[†]). Notable to mention that the symmetry assignments, σ and π in Table 3 have been made with respect to the $C_{cAAC-P-Si-C_L}$ plane. The strongest interaction, $\Delta E_{orb(1)}$ (36.6–45.8%) comes from electron sharing σ interaction in out-of-phase (+–) combination of the unpaired electrons in the SOMO of the fragments. The dative in-phase (++) σ donation from HOMO of the ligands [(cAAC)(L)]⁺ into LUMO of the [P–Si(Cl)][–] forms the slightly weaker $\Delta E_{orb(2)}$ (23.3–26.1%) in 1-Cl, 2-Cl and much weaker (12.1%) in 4-Cl. In 1-Cl along with in-phase (++) σ donation, the backdonation from HOMO–1 of [P–Si(Cl)][–] to LUMO+1 of ligands [(cAAC)(L)]⁺ contributes to $\Delta E_{orb(2)}$. The $\Delta E_{orb(3)}$ is due to π backdonation from HOMO of [P–Si(Cl)][–] to LUMO of ligands [(cAAC)(L)]⁺ and contributes 15.1–17% in 1-Cl,

2-Cl and 30% in 4-Cl. The strength of π contribution is significantly high in 4-Cl compared to 1-Cl and 2-Cl. While, the other weak interaction, $\Delta E_{orb(4)}$ (4.6–13.4%) in 1-Cl is due to σ donation from HOMO of the ligands [(cAAC)(L)]⁺ into LUMO of the [P–Si(Cl)][–], in 2-Cl it is due to σ backdonation from HOMO–1 of [P–Si(Cl)][–] to LUMO+1 of ligands [(cAAC)(L)]⁺ and 4-Cl it is due to π back-donation. The last and very weak contribution, $\Delta E_{orb(5)}$ (2.6–2.8%) is a backdonation from [P–Si(Cl)][–], majorly into the SOMO and to a little extent into the higher lying vacant orbitals of the ligands [(cAAC)(L)]⁺. In case of 3-Cl, the cAAC–PSi(Cl)–L (L = PMe₃) bonds are 52.6% covalent in nature and the remaining part is shared by coulombic or electrostatic interaction (44.1%) and dispersion interaction (3.3%). Thus the cAAC–PSi(Cl)–L bonds in 3-Cl are more covalent in nature

Table 2 EDA-NOCV results of cAAC–P–Si(Cl)–L (L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC) compounds using five different sets of fragments with different charges and electronic states (S = singlet, D = doublet, T = triplet, Q = quintet) and associated bond types at the BP86–D3(BJ)/TZ2P level. Energies are in kcal mol^{−1}. The most favourable fragmentation scheme and bond type is given by the smallest ΔE_{orb} value written in bold

Molecule	Bond type ^a	Fragments	ΔE_{int}	ΔE_{Pauli}	ΔE_{elstat}	ΔE_{disp}	ΔE_{orb}
cAAC–P–Si(Cl)–cAAC	D	(cAAC ^{Me}) ₂ (S) + P–Si(Cl) (S)	−205.8	651.3	−408.9	−23.6	−424.7
	E (σ, π)	(cAAC ^{Me}) ₂ (T) + P–Si(Cl) (T)	−339.9	556.0	−344.8	−23.6	−527.6
	E (σ, σ)	(cAAC ^{Me}) ₂ (T) + P–Si(Cl) (T)	−218.3	609.5	−371.8	−23.6	−432.4
	D + E	[(cAAC ^{Me}) ₂] ⁺ (D) + [P–Si(Cl)] [−] (D)	−252.5	622.1	440.2	−23.6	−410.8
	E	(cAAC ^{Me}) ₂ (Q) + P–Si(Cl) (Q)	−304.7	499.9	−341.0	−23.6	−440.0
cAAC–P–Si(Cl)–NHC	D	[(cAAC ^{Me})(NHC ^{Me})] (S) + P–Si(Cl) (S)	−192.1	548.3	−356.6	−21.9	−362.0
	E (σ, π)	[(cAAC ^{Me})(NHC ^{Me})] (T) + P–Si(Cl) (T)	−203.2	487.7	−312.9	−21.9	−356.1
	E (σ, σ)	[(cAAC ^{Me})(NHC ^{Me})] (T) + P–Si(Cl) (T)	−369.4	507.0	−332.6	−21.9	−521.8
	D + E	[(cAAC ^{Me})(NHC ^{Me})] ⁺ (D) + [P–Si(Cl)] [−] (D)	−246.3	514.6	−390.6	−21.9	−348.5
	E	[(cAAC ^{Me})(NHC ^{Me})] (Q) + P–Si(Cl) (Q)	−334.7	436.8	−299.5	−21.9	−450.2
cAAC–P–Si(Cl)–PMe ₃	D	[(cAAC ^{Me})(PMe ₃)] (S) + P–Si(Cl) (S)	−177.1	743.7	−391.3	−21.5	−507.9
	E (σ, π)	[(cAAC ^{Me})(PMe ₃)] (T) + P–Si(Cl) (T)	−189.4	465.9	−289.2	−21.5	−344.6
	E (σ, σ)	[(cAAC ^{Me})(PMe ₃)] (T) + P–Si(Cl) (T)	−359.2	517.7	−297.7	−21.5	−557.7
	D + E	[(cAAC ^{Me})(PMe ₃)] ⁺ (D) + [P–Si(Cl)] [−] (D)	−236.9	651.7	−427.8	−21.5	−439.3
	E	[(cAAC ^{Me})(PMe ₃)] (Q) + P–Si(Cl) (Q)	−339.1	429.1	−282.7	−21.5	−464.0
cAAC–P–Si(Cl)–aAAC	D	[(cAAC ^{Me})(aAAC)] (S) + P–Si(Cl) (S)	−222.6	684.8	−428.6	−26.6	−452.2
	E (σ, π)	[(cAAC ^{Me})(aAAC)] (T) + P–Si(Cl) (T)	−198.9	717.4	−415.7	−26.6	−473.8
	E (σ, σ)	[(cAAC ^{Me})(aAAC)] (T) + P–Si(Cl) (T)	−321.4	605.8	−370.5	−26.6	−530.0
	D + E	[(cAAC ^{Me})(aAAC)] ⁺ (D) + [P–Si(Cl)] [−] (D)	−259.4	675.8	−469.4	−26.6	−439.1
	E	[(cAAC ^{Me})(aAAC)] (Q) + P–Si(Cl) (Q)	−288.9	556.2	−369.9	−26.6	−448.5

^a D = dative bond; E = electron sharing bond.

compared to those of **1-Cl** and **2-Cl**. Similar to the other two compounds, there are five significant orbital terms, $\Delta E_{\text{orb}(1)} - \Delta E_{\text{orb}(5)}$ in **3-Cl**. The strongest interaction, $\Delta E_{\text{orb}(1)}$ (37.9%) comes from the electron sharing σ interaction in out-of-phase (+−) combination of the unpaired electrons in the SOMO−1 of the fragments. The third orbital term, $\Delta E_{\text{orb}(3)}$ (35.7%) is as strong as $\Delta E_{\text{orb}(1)}$ and is due to electron sharing π interaction of the unpaired electrons in the SOMO of the fragments. $\Delta E_{\text{orb}(2)}$ term is a dative in-phase (++) σ donation from HOMO of the

ligands [(cAAC)(L)] into LUMO of the P–Si(Cl). It is rather weak (14.1%) compared to σ and π electron sharing contributions. The other two orbital terms, $\Delta E_{\text{orb}(4)}$ and $\Delta E_{\text{orb}(5)}$ are due to σ back donations from HOMO and HOMO−3 of P–Si(Cl) into higher lying LUMO+13 and LUMO+2 vacant orbitals of [(cAAC)(L)] ligands, respectively.

Similarly, we have analyzed cAAC–P–Si(F)–L bonds of the fluoro-substituted cAAC–P–Si(F)–L (L = cAAC^{Me}, NHC^{Me}, PMe₃) compounds **1-F** to **4-F**, using EDA-NOCV by considering five

Table 3 The EDA-NOCV results at the BP86–D3(BJ)/TZ2P level of cAAC–P–Si(Cl)–L bonds of cAAC–P–Si(Cl)–L (L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC) using [(cAAC)(L)]⁺ and [P–Si(Cl)][−] in the electronic doublet (D) states as interacting fragments for L = cAAC^{Me}, NHC^{Me}, aAAC and neutral [(cAAC)(L)] and P–Si(Cl) in the triplet (T) state as interacting fragments for L = PMe₃. Energies are in kcal mol^{−1}

Energy	Interaction	[(cAAC) ₂] ⁺ (D) + [P–Si(Cl)] [−] (D)	[(cAAC)(NHC)] ⁺ (D) + [P–Si(Cl)] [−] (D)	[(cAAC)(PMe ₃)] (T) + P–Si(Cl) (T)	[(cAAC)(aAAC)] ⁺ (D) + [P–Si(Cl)] [−] (D)
ΔE_{int}		−252.5	−246.3	−189.4	−259.4
ΔE_{Pauli}		622.1	514.6	465.9	675.8
ΔE_{disp}		−23.6 (2.6%)	−21.9 (2.9%)	−21.5 (3.3%)	−26.6 (2.8%)
ΔE_{elstat}		−440.2 (50.3%)	−390.6 (51.3%)	−289.2 (44.1%)	−469.4 (50.2%)
ΔE_{orb}		−410.8 (46.9%)	−348.5 (45.8%)	−344.6 (52.6%)	−439.1 (47%)
$\Delta E_{\text{orb}(1)}$	cAAC–P–Si(Cl)–L σ e [−] sharing (+,−)	−163.0 (39.6%)	−159.8 (45.8%)	−130.6 (37.9%)	−157.9 (36%)
$\Delta E_{\text{orb}(2)}$	cAAC→P–Si(Cl)←L σ donation (+,+)	−107.2 (26.1%)	−81.4 (23.3%)	−48.5 (14.1%)	−53.0 (12.1%)
$\Delta E_{\text{orb}(3)}$	cAAC–P–Si(Cl)–L π e [−] sharing			−123.2 (35.7%)	
	cAAC←P–Si(Cl)→L π back donation	−62.2 (15.1%)	−59.2 (17.0%)		−131.2 (30%)
$\Delta E_{\text{orb}(4)}$	cAAC→P–Si(Cl)←L σ donation	−43.9 (10.7%)			
	cAAC←P–Si(Cl)→L back donation		−16.1 (4.6%)	−14.8 (4.3%)	−59.1 (13.4%)
$\Delta E_{\text{orb}(5)}$	cAAC←P–Si(Cl)→L back donation	−10.7 (2.6%)	−9.8 (2.8%)	−6.8 (1.9%)	−11.1 (2.5%)
$\Delta E_{\text{orb}(\text{rest})}$		−23.8 (5.8%)	−22.2 (6.3%)	−20.7 (6.0%)	−26.8 (6.1%)

^a The values in the parentheses show the contribution to the total attractive interaction $\Delta E_{\text{elstat}} + \Delta E_{\text{orb}} + \Delta E_{\text{disp}}$. ^b The values in parentheses show the contribution to the total orbital interaction ΔE_{orb} .

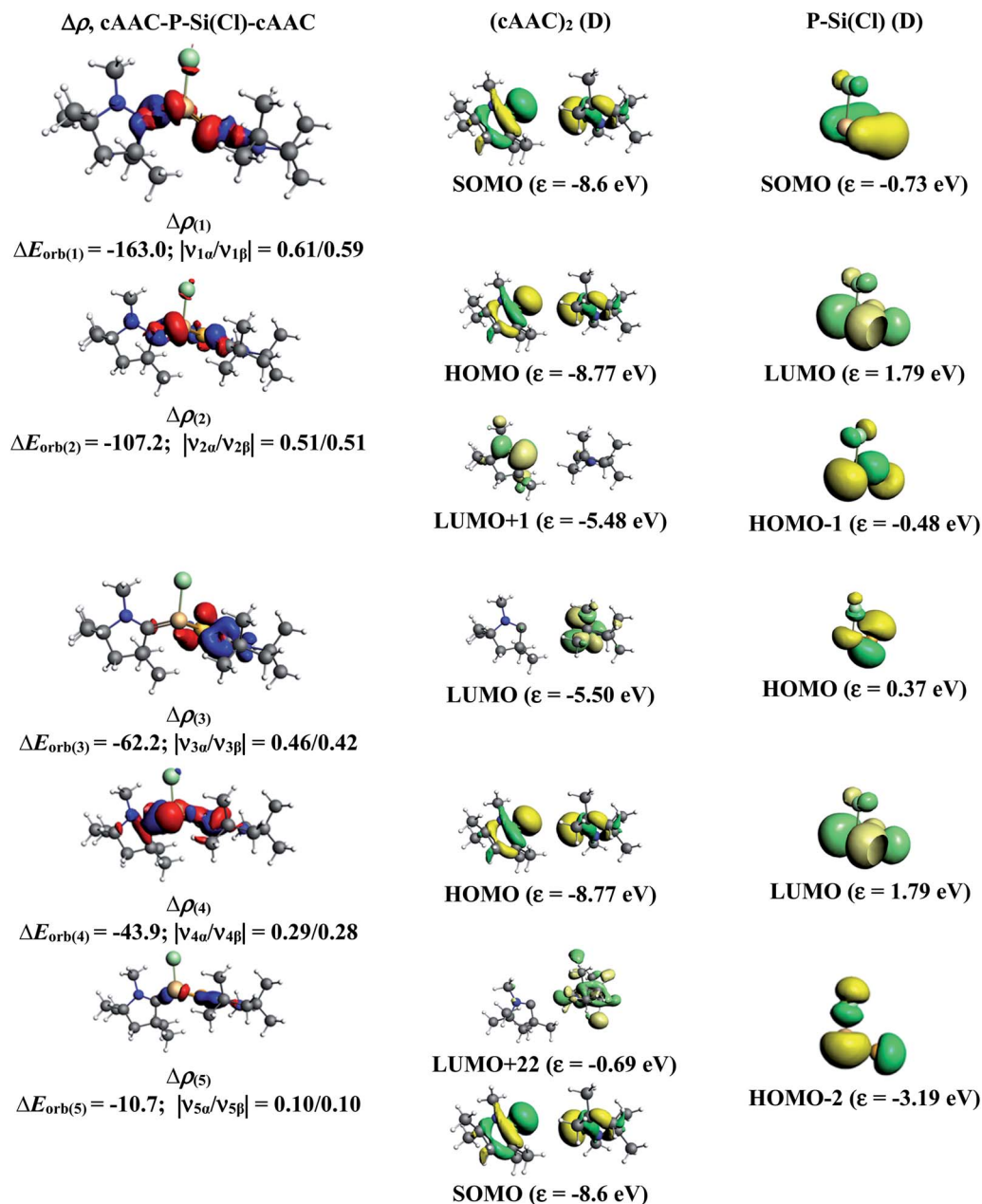


Fig. 3 The shape of the deformation densities, $\Delta\rho_{(1)-(5)}$ that correspond to $\Delta E_{\text{orb}(1)-(5)}$, and the associated MOs of cAAC-P-Si(Cl)-cAAC and the fragments orbitals of [(cAAC)₂]⁺ and [P-Si-Cl]⁻ in the doublet state at the BP86-D3(BJ)/TZ2P level. Isosurface values are 0.003 au. The eigenvalues $|\nu_n|$ give the size of the charge migration in e. The direction of the charge flow of the deformation densities is red → blue.

different bonding possibilities on the similar lines of chloro-substituted complexes 1-Cl to 3-Cl. EDA-NOCV results from Table 4 suggests that for 1-F, the fragmentation scheme involving singly charged [(cAAC)(L)]⁺ and [P-Si(F)]⁻ fragments in electronic doublet state forming both electron sharing and dative bonds gives the best bonding description. It is to be observed that for 1-F bonding possibility (1) forming dative bonds also have comparable ΔE_{orb} value with the best bonding possibility (4), indicating that the dative bonding model might also be valid in describing the bonding. Whereas, for 2-F and 3-F, the best bonding description of cAAC-PSi(F)-L bonds comes from the interaction of neutral [(cAAC)(L)] and P-Si(Cl/F)

fragments in triplet electronic state forming σ and π electron sharing bonds and other σ and π dative bonds. Interestingly, for complex 4-F, the best bonding description comes almost equally from two bonding possibilities, (4) and (5), where the bonding can be explained in terms of mixture of electron sharing and dative bonds (4), as well as all electron sharing bonds (5), since, ΔE_{orb} value differ by less than 1 kcal mol⁻¹. It is to be noted that the fluoro-substituted compound cAAC-PSi(F)-NHC (2-F), in contrast to its chloro substituted counterpart (2-Cl), prefers to form σ and π electron sharing cAAC-PSi(F)-L bonds with interacting fragments in triplet state. This change in bonding preference is in agreement with the significant

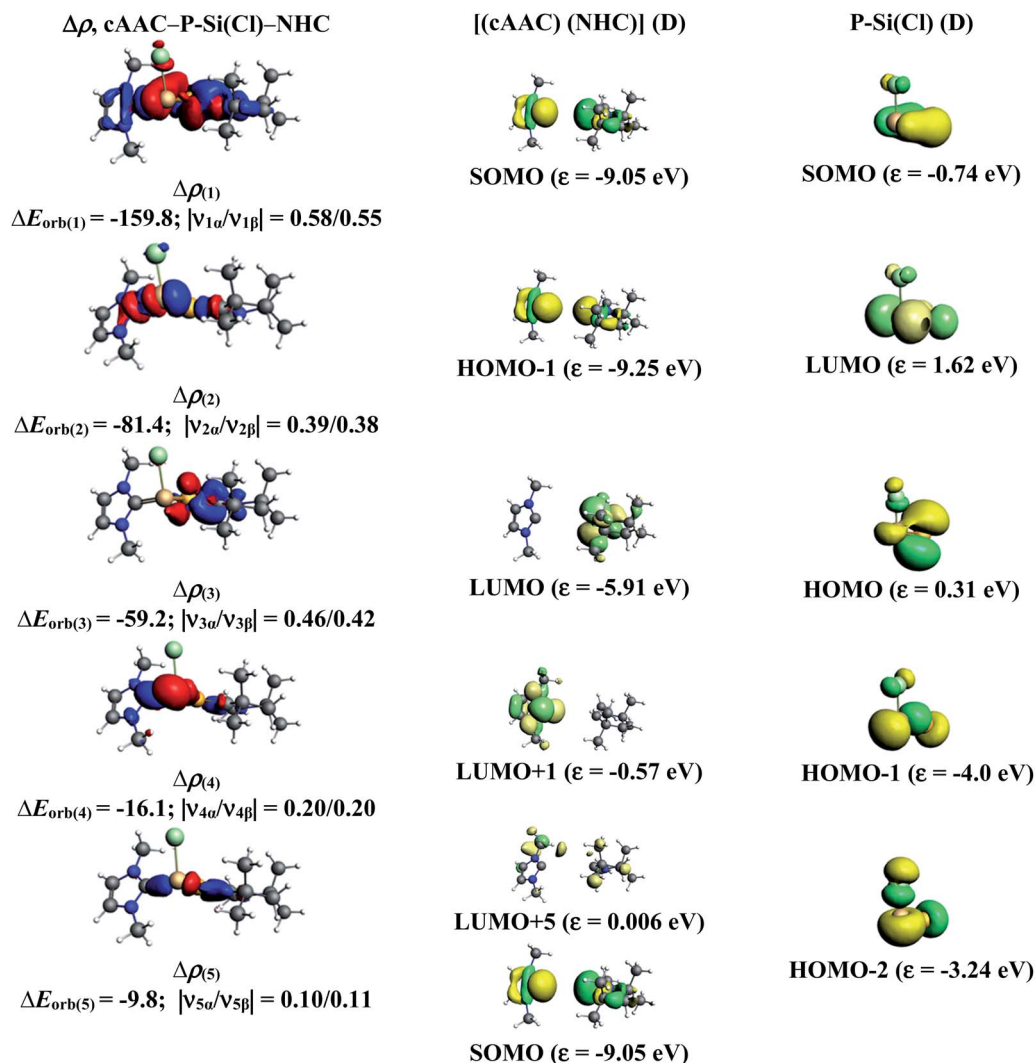


Fig. 4 The shape of the deformation densities, $\Delta\rho_{(1)-(5)}$ that correspond to $\Delta E_{\text{orb}(1)-(5)}$, and the associated MOs of cAAC-P-Si(Cl)-NHC and the fragments orbitals of $[(\text{cAAC})(\text{NHC})]^+$ and $[\text{P-Si-Cl}]^-$ in the doublet state at the BP86-D3(BJ)/TZ2P level of theory. Isosurface values are 0.003 au for $\Delta\rho_{(1)-(3)}$ and isosurface value 0.001 for $\Delta\rho_{(4)-(5)}$. The eigenvalues $|v_n|$ give the size of the charge migration in e. The direction of the charge flow of the deformation densities is from red \rightarrow blue.

increase in C-P-Si-C torsion angle for fluoro-substituted complex (Fig. 1), which might have altered the PSi(F)-L orbital interactions.

The numerical results from Table 5 gives the detailed information on the pairwise interactions of cAAC-PSi(F)-L bonds. cAAC-PSi(F)-L bonds in **2-F** (51.4%), **3-F** (52.7%) and **4-F** (53%) are more covalent in nature compared to **1-F** (46.7%). There are five orbital terms, $\Delta E_{\text{orb}(1)}-\Delta E_{\text{orb}(5)}$ and associated deformation densities, $\Delta\rho_n$ (Fig. S6-S9[†]) for all three compounds **1-F** to **4-F**. For **1-F**, the strongest interaction, $\Delta E_{\text{orb}(1)}$ (40.3%) comes from electron sharing σ interaction in out-of-phase (+-) combination of the unpaired electrons in the SOMO of the fragments. The dative in-phase (++) σ donation from HOMO of the ligands $[(\text{cAAC})(\text{L})]^+$ into LUMO of the $[\text{P-Si(F)}]^-$ forms the slightly weaker $\Delta E_{\text{orb}(2)}$ (25.3%). Along with in-phase (++) σ donation, the back donation from HOMO-1 of $[\text{P-Si(F)}]^-$ to LUMO+1 of ligands $[(\text{cAAC})(\text{L})]^+$ contributes to

$\Delta E_{\text{orb}(2)}$. The $\Delta E_{\text{orb}(3)}$ (15.0%) is due to π backdonation from HOMO of $[\text{P-Si(F)}]^-$ to LUMO of ligands $[(\text{cAAC})(\text{L})]^+$. The σ contribution is higher compared to π contribution. While, the other weak interaction $\Delta E_{\text{orb}(4)}$ (11.5%) is due to σ donation from HOMO of the ligands $[(\text{cAAC})(\text{L})]^+$ into LUMO of the $[\text{P-Si(F)}]^-$. The last and very weak contribution, $\Delta E_{\text{orb}(5)}$ (2.6%) is a backdonation from HOMO-2 of $[\text{P-Si(F)}]^-$ into the SOMO of ligands $[(\text{cAAC})(\text{L})]^+$. Whereas, in case of complexes **2-F** and **3-F**, the strongest interaction, $\Delta E_{\text{orb}(1)}$ (45.2-46.5%) comes from the electron-sharing σ interaction in out-of-phase (+-) combination of the unpaired electrons in the SOMO-1 of the fragments. Third orbital term $\Delta E_{\text{orb}(3)}$ (20.5-28.5%) is slightly weaker than $\Delta E_{\text{orb}(1)}$ and is due to electron sharing π interaction of the unpaired electrons in the SOMO of the fragments. $\Delta E_{\text{orb}(2)}$ term is a dative in-phase (++) σ donation from HOMO of the ligands $[(\text{cAAC})(\text{L})]$ into LUMO of the P-Si(F) . It is equivalent to π interaction in complex **2-F** (20.1%) and rather weak (13.2%) in

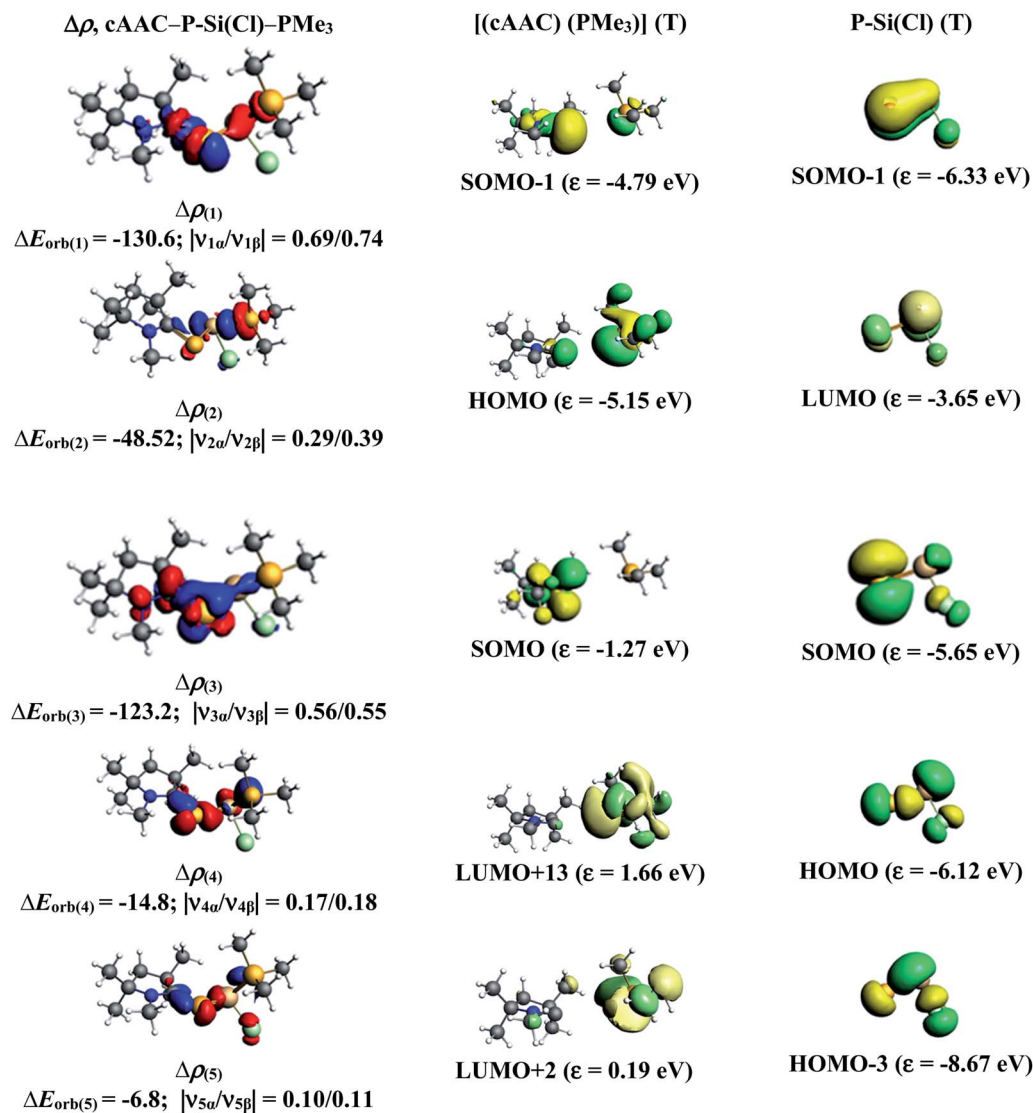


Fig. 5 The shape of the deformation densities, $\Delta\rho_{(1)-(5)}$ that correspond to $\Delta E_{\text{orb}(1)-(5)}$, and the associated MOs of cAAC-P-Si(Cl)-PMe₃ and the fragments orbitals of [(cAAC)(PMe₃)] and [P-Si-Cl] in the triplet state at the BP86-D3(BJ)/TZ2P level. Isosurface values are 0.003 au. The eigenvalues $|\nu_n|$ give the size of the charge migration in e. The direction of the charge flow of the deformation densities is red \rightarrow blue.

complex 3-F. The other two orbital terms $\Delta E_{\text{orb}(4)}$ and $\Delta E_{\text{orb}(5)}$ are due to σ back donations from HOMO and HOMO-1 of P-Si(F) in to LUMO+1 and SOMO-1 orbitals of [(cAAC)L] ligands, respectively in compound 2-F. The orbital terms $\Delta E_{\text{orb}(4)}$ and $\Delta E_{\text{orb}(5)}$ in 3-F are σ backdonations from HOMO and HOMO-3 of P-Si(F) in to LUMO+3 and LUMO+2 orbitals of [(cAAC)(L)] ligands. In 4-F, the four significant orbital terms, $\Delta E_{\text{orb}(1)}$ - $\Delta E_{\text{orb}(4)}$ between the neutral fragments in the quintet states are identified as strong in-phase (+,+) and out-of-phase (+,-) electron sharing σ interactions, $\Delta E_{\text{orb}(1)}$ and $\Delta E_{\text{orb}(2)}$ and the weaker but still rather strong π interactions, $\Delta E_{\text{orb}(3)}$ and $\Delta E_{\text{orb}(4)}$. The weaker $\Delta E_{\text{orb}(5)}$ is a σ interaction between HOMO-2 of P-Si(F) and SOMO- of [(cAAC)(L)] ligands.

We have further focussed our study on understanding the nature of P-Si bonds of all cAAC-PSi(Cl/F)-L (L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC) molecules (1-Cl to 4-Cl and 1-F to 4-F). We

have considered three different bonding possibilities (Scheme 3) by varying the charge and electronic states of the interacting fragments, cAAC-P and Si(Cl/F)-L, viz., (1) neutral cAAC-P and Si(Cl/F)-L fragments in their electronic doublet states leading to the formation of electron sharing and dative bonds, (2) singly charged [cAAC-P]⁻ and [Si(Cl/F)-L]⁺ fragments in electronic singlet state forming dative bonds and (3) singly charged [cAAC-P]⁺ and [Si(Cl/F)-L]⁻ fragments in electronic singlet state forming dative bonds. EDA-NOCV results from Tables 6 and S3† show that the best bonding description of central P-Si bond in all eight compounds (1-Cl to 4-Cl and 1-F to 4-F) comes from the interaction of neutral fragments in doublet state forming electron sharing and dative bonds. Whereas, the best bonding description of P-Si bond in unsubstituted P-Si(Cl) comes from the interaction of neutral P and Si(Cl) fragments in quartet state forming three electron sharing bonds (Table S17†). This change

Table 4 EDA-NOCV results of cAAC–PSi(F)–L bonds of cAAC–P–Si(F)–L (L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC) using five different sets of fragments with different charges and electronic states (S = singlet, D = doublet, T = triplet, Q = quintet) and associated bond types at the BP86–D3(BJ)/TZ2P level of theory. Energies are in kcal mol^{−1}. The most favourable fragmentation scheme and bond type are given by the smallest ΔE_{orb} value (written in bold)

Molecule	Bond type ^a	Fragments	ΔE_{int}	ΔE_{Pauli}	ΔE_{elstat}	ΔE_{disp}	ΔE_{orb}
cAAC–P–Si(F)–cAAC	D	(cAAC ^{Me}) ₂ (S) + P–Si(F) (S)	−203.9	638.2	−406.3	−21.3	−414.6
	E (σ, π)	(cAAC ^{Me}) ₂ (T) + P–Si(F) (T)	−216.5	601.6	−370.2	−21.3	−426.6
	E (σ, σ)	(cAAC ^{Me}) ₂ (T) + P–Si(F) (T)	−344.3	553.5	−347.6	−21.3	−528.7
	D + E	[(cAAC ^{Me}) ₂] ⁺ (D) + [P–Si(F)] [−] (D)	−252.7	619.9	−443.5	−21.3	−407.8
	E	(cAAC ^{Me}) ₂ (Q) + P–Si(F) (Q)	−305.8	498.2	−345.8	−21.3	−436.8
cAAC–P–Si(F)–NHC	D	[(cAAC ^{Me})(NHC ^{Me})] (S) + P–Si(F) (S)	−188.0	575.8	−367.3	19.4	−377.1
	E (σ, π)	[(cAAC ^{Me})(NHC ^{Me})] (T) + P–Si(F) (T)	−199.9	495.8	−319.1	−19.4	−357.3
	E (σ, σ)	[(cAAC ^{Me})(NHC ^{Me})] (T) + P–Si(F) (T)	−373.1	526.7	−339.8	−19.4	−540.6
	D + E	[(cAAC ^{Me})(NHC ^{Me})] ⁺ (D) + [P–Si(F)] [−] (D)	−346.2	497.5	−338.5	−19.4	−485.7
	E	[(cAAC ^{Me})(NHC ^{Me})] (Q) + P–Si(F) (Q)	−248.0	543.8	−405.1	−19.4	−367.4
cAAC–P–Si(F)–PMe ₃	D	[(cAAC ^{Me})(PMe ₃)] (S) + P–Si(F) (S)	−169.7	711.8	−377.3	−19.3	−484.8
	E (σ, π)	[(cAAC ^{Me})(PMe ₃)] (T) + P–Si(F) (T)	−184.0	447.1	−279.2	−19.3	−332.6
	E (σ, σ)	[(cAAC ^{Me})(PMe ₃)] (T) + P–Si(F) (T)	−373.5	564.8	−313.2	−19.3	−605.8
	D + E	[(cAAC ^{Me})(PMe ₃)] ⁺ (D) + [P–Si(F)] [−] (D)	−234.2	631.5	−421.1	−19.3	−425.2
	E	[(cAAC ^{Me})(PMe ₃)] (Q) + P–Si(F) (Q)	−336.8	402.3	−268.9	−19.3	−450.9
cAAC–P–Si(F)–aAAC	D	[(cAAC ^{Me})(aAAC)] (S) + P–Si(F) (S)	−219.4	691.0	−433.0	−23.6	−453.8
	E (σ, π)	[(cAAC ^{Me})(aAAC)] (T) + P–Si(F) (T)	−197.1	719.0	−416.6	−23.6	−475.9
	E (σ, σ)	[(cAAC ^{Me})(aAAC)] (T) + P–Si(F) (T)	−327.4	602.9	−373.4	−23.6	−533.4
	D + E	[(cAAC ^{Me})(aAAC)] ⁺ (D) + [P–Si(F)] [−] (D)	−260.1	691.4	−480.9	−23.6	−447.0
	E	[(cAAC ^{Me})(aAAC)] (Q) + P–Si(F) (Q)	−290.7	552.5	−373.3	−23.6	−446.3

^a D = dative bond; E = electron sharing bond.

in nature of bonding is owed to the presence of donor ligands which weakens the P–Si bond.

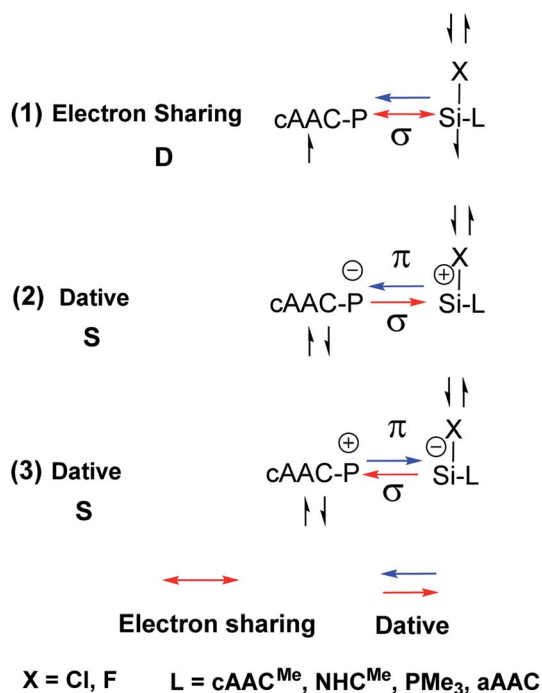
Further analysis of the best bonding description indicates four pairwise interactions $\Delta E_{\text{orb}(1)} - \Delta E_{\text{orb}(4)}$ in all the compounds (Tables 7 and S4[†]) (Fig. 6–8, S5 and S10–S13[†]). The strongest interaction $\Delta E_{\text{orb}(1)}$ (77.5–81.4%) is due to the electron sharing σ

interaction of the unpaired electrons in the SOMO of the fragments. The second orbital term, $\Delta E_{\text{orb}(2)}$ is a π donation from HOMO of cAAC–P into LUMO of Si(Cl/F)–L and contributes 6.3–9.2% to the total orbital interaction. The π contributions are very weak compared to the σ contributions. The remaining two orbital terms, $\Delta E_{\text{orb}(3)}$ and $\Delta E_{\text{orb}(4)}$ are from weak σ/π donation

Table 5 The EDA-NOCV results at the BP86–D3(BJ)/TZ2P level of cAAC–PSi(F)–L bonds of cAAC–P–Si(Cl)–L (L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC) using [(cAAC)(L)]⁺ and [P–Si(F)][−] in the electronic doublet (D) states as interacting fragments for L = cAAC^{Me}, neutral [(cAAC)(L)] and P–Si(F) in the triplet (T) state as interacting fragments for L = NHC^{Me}, PMe₃ and neutral [(cAAC)(L)] and P–Si(F) in the electronic quartet state for L = aAAC. Energies are in kcal mol^{−1}

Energy	Interaction	[(cAAC) ₂] ⁺ (D) + [P–Si(F)] [−] (D)	[(cAAC)(NHC)] (T) + P–Si(F) (T)	[(cAAC)(PMe ₃)] (T) + P–Si(F) (T)	[(cAAC)(aAAC)] (Q) + P–Si(F) (Q)
ΔE_{int}		−252.7	−199.9	−184.0	−290.7
ΔE_{Pauli}		619.9	495.8	447.1	552.5
ΔE_{disp}^a		−21.3 (2.4%)	−19.4 (2.8%)	−19.3 (3.0%)	−23.6 (2.8%)
$\Delta E_{\text{elstat}}^a$		−443.5 (50.8%)	−319.1 (45.8%)	−279.2 (44.3%)	−373.3 (44.2%)
ΔE_{orb}^a		−407.8 (46.7%)	−357.3 (51.4%)	−332.6 (52.7%)	−446.3 (53%)
$\Delta E_{\text{orb}(1)}^b$	cAAC–P–Si(F)–L σ e [−] sharing (+,−)	−164.6 (40.3%)	−161.7 (45.2%)	−154.6 (46.5%)	−136.1 (30.5%)
$\Delta E_{\text{orb}(2)}^b$	cAAC → P–Si(F) ← L σ donation (+,+)	−102.3 (25.3%)	−72.0 (20.1%)	44.0 (13.2%)	
	cAAC → P–Si(F) ← L σ e [−] sharing (+,+)				−146.5 (32.8%)
$\Delta E_{\text{orb}(3)}^b$	cAAC–P–Si(F)–L π e [−] sharing		−73.4 (20.5%)	−95.0 (28.5%)	−65.8 (14.7%)
	cAAC ← P–Si(F) → L π back donation	−61.3 (15.0%)			
$\Delta E_{\text{orb}(4)}^b$	cAAC → P–Si(F) ← L σ donation	−47.0 (11.5%)			
	cAAC ← P–Si(F) → L σ back donation		−19.5 (5.4%)	−15.6 (4.7%)	
	cAAC–P–Si(F)–L π e [−] sharing				−59.3 (13.3%)
$\Delta E_{\text{orb}(5)}^b$	cAAC ← P–Si(F) → L σ back donation	−10.8 (2.6%)	−10.5 (2.9%)	−7.4 (2.2%)	−12.6 (2.8%)
$\Delta E_{\text{orb}(\text{rest})}^b$		−21.8 (5.3%)	−20.2 (5.6%)	−16.0 (4.8%)	−26 (5.8%)

^a The values in the parentheses show the contribution to the total attractive interaction, $\Delta E_{\text{elstat}} + \Delta E_{\text{orb}} + \Delta E_{\text{disp}}$. ^b The values in parentheses show the contribution to the total orbital interaction, ΔE_{orb} .



Scheme 3 Bonding possibilities of cAAC–P–Si(X)–L bond of cAAC–P–Si(X)–L (L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC; X = Cl, F) 1-Cl to 4-Cl and 1-F to 4-F.

and back donations and are slightly different due to the improper molecular planes of the two fragments. In all compounds, the P–Si bond is slightly more covalent in nature rather with significant coulombic or electrostatic interaction. The pairwise interactions of P–Si bond in donor ligand free P–Si(Cl) molecule indicates strong electron sharing σ interaction and two equally contributing, rather strong electron sharing π interactions (Table S18 and Fig. S25†).

We have modelled and optimized the geometries of compounds, L–PSi(X) and L–Si(X)P (L = cAAC^{Me}, NHC^{Me}, PMe₃,

aAAC) (X = Cl, F) to shed light on the effect of single donor ligand on P and Si atoms in bonding and stabilization of such species. The singlet states of all the compounds are found to be lower in energy than the corresponding triplet states by 30.16 to 36.53 kcal mol^{−1} in case of L–PSi(X) and 8.16 to 21.0 kcal mol^{−1} in case of L–Si(X)P [L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC; X = Cl, F]. The higher singlet–triplet energy gap (ΔE_{S-T}) indicates higher stability of L–PSi(X) compared to L–Si(X)P. The optimized geometries of P-bonded L–PSi(X) compounds (Fig. S15†) show that the chlorine atom is oriented *cis* to the cAAC ligand in cAAC–PSi(Cl), whereas the fluorine atom is *trans* to the cAAC ligand in cAAC–PSi(F). The shift in halogen orientation is supported by the change in C–P–Si–X (X = Cl/F) torsion angle from 2.2° (cAAC–PSi(Cl)) to 3.4° (cAAC–PSi(F)) and can lead to a difference in L–P bonding in these compounds. Similar situation is observed in compounds with L = aAAC. The replacement of chlorine with fluorine caused in large shift in C–P–Si–X (X = Cl/F) torsion angle from 177.1° in aAAC–PSi(Cl) to 5.2° in aAAC–PSi(F). The C–P–Si–X (X = Cl/F) torsion angle of 0.0° in L–PSi(X) with L = NHC^{Me}, PMe₃ shows that the halogen atom is in the same plane of the ligand. The optimised structures of the Si bonded compounds L–Si(X)P are shown in Fig. S16.† The optimized geometries indicate that the Si(X)P unit is almost perpendicular to the ligand in all compounds with L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC (X = Cl, F). The acute C–Si–P bond angle of 66.8° indicates a C–Si–P semi-bridging possibility. The L–Si bond lengths in compounds L–Si(X)P are slightly longer compared to the L–Si bond lengths in cAAC–PSi(X)–L with L = cAAC^{Me}, aAAC and are slightly shorter in case of L–Si(X) with L = NHC^{Me}, PMe₃.

The dissociation energies, D_e of L–P/Si bonds in L–PSi(X) and L–Si(X)P compounds were calculated at BP86-D3(BJ)/Def2-TZVPP level to understand the thermodynamic stability of these species. The comparison of results in Tables S5 and S6† show higher dissociation energy for L–P bonds (52–78 kcal mol^{−1}) than L–Si bonds (35–69 kcal mol^{−1}). The

Table 6 EDA-NOCV results of cAAC–P–Si(Cl)–L bond of cAAC–P–Si(Cl)–L (L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC) using three different sets of fragments with different charges and electronic states (S = singlet, D = doublet) and associated bond types at the BP86-D3(BJ)/TZ2P level of theory. Energies are in kcal mol^{−1}. The most favourable fragmentation scheme and bond type are given by the smallest ΔE_{orb} value (written in bold)

Molecule	Bond type ^a	Fragments	ΔE_{int}	ΔE_{Pauli}	ΔE_{elstat}	ΔE_{disp}	ΔE_{orb}
cAAC–P–Si(Cl)–cAAC	E	cAAC ^{Me} –P (D) + Si(Cl)–cAAC ^{Me} (D)	−62.8	200.6	−119.9	−13.7	−129.8
	D	[cAAC ^{Me} –P] [−] (S) + [Si(Cl)–cAAC ^{Me}] ⁺ (S)	−194.9	265.5	−239.6	−13.7	−207.1
	D	[cAAC ^{Me} –P] ⁺ (S) + [Si(Cl)–cAAC ^{Me}] [−] (S)	−211.7	222.7	−202.7	−13.7	−218.0
cAAC–P–Si(Cl)–NHC	E	cAAC ^{Me} –P (D) + Si(Cl)–NHC ^{Me} (D)	−60.5	188.1	−113.6	−12.1	−123.0
	D	[cAAC ^{Me} –P] [−] (S) + [Si(Cl)–NHC ^{Me}] ⁺ (S)	−178.3	230.7	−224.2	−12.1	−172.7
	D	[cAAC ^{Me} –P] ⁺ (S) + [Si(Cl)–NHC ^{Me}] [−] (S)	−223.8	230.2	−209.7	−12.1	232.2
cAAC–P–Si(Cl)–PMe ₃	E	cAAC ^{Me} –P (D) + Si(Cl)–PMe ₃ (D)	−64.2	192.0	−119.8	−13.2	−123.1
	D	[cAAC ^{Me} –P] [−] (S) + [Si(Cl)–PMe ₃] ⁺ (S)	−192.7	226.5	−231.0	−13.2	−174.9
	D	[cAAC ^{Me} –P] ⁺ (S) + [Si(Cl)–PMe ₃] [−] (S)	−229.8	253.3	−231.1	−13.2	−238.7
cAAC–P–Si(Cl)–aAAC	E	cAAC ^{Me} –P (D) + Si(Cl)–aAAC (D)	−65.5	200.5	−120.0	−14.0	−131.8
	D	[cAAC ^{Me} –P] [−] (S) + [Si(Cl)–aAAC] ⁺ (S)	−205.4	264.7	−241.6	−14.0	−214.8
	D	[cAAC ^{Me} –P] ⁺ (S) + [Si(Cl)–aAAC] [−] (S)	−203.8	219.4	−196.4	−14.0	−212.6

^a D = dative bond; E = electron sharing bond.

Table 7 The EDA-NOCV results at the BP86-D3(BJ)/TZ2P level of theory for cAAC-P-Si(Cl)L bond of cAAC-P-Si(Cl)-L (L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC) using (cAAC-P) and (Si(Cl)-L) in the electronic doublet (D) states as interacting fragments. Energies are in kcal mol⁻¹

Energy	Interaction	cAAC-P (D) + Si(Cl)-cAAC (D)	cAAC-P (D) + Si(Cl)-NHC (D)	cAAC-P (D) + Si(Cl)-PMe ₃ (D)	cAAC-P (D) + Si(Cl)-aAAC (D)
ΔE_{int}		-62.8	-60.5	-64.2	-65.5
ΔE_{Pauli}		200.6	188.1	192.0	200.5
ΔE_{disp}^a		-13.7 (5.2%)	-12.1 (4.8%)	-13.2 (5.2%)	-14.0 (5.2%)
$\Delta E_{\text{elstat}}^a$		-119.9 (45.5%)	-113.6 (45.7%)	-119.8 (46.7%)	-120.0 (45.2%)
ΔE_{orb}^a		-129.8 (49.3%)	-122.9 (49.5%)	-123.1 (48.1%)	-131.9 (49.6%)
$\Delta E_{\text{orb}(1)}^b$	cAAC-P-Si(Cl)L σ e ⁻ sharing	-100.6 (77.5%)	-98.9 (80.4%)	-99.3 (80.6%)	-100.6 (76.2%)
$\Delta E_{\text{orb}(2)}^b$	cAAC-P \rightarrow Si(Cl)L π donation	-11.1 (8.5%)	-7.8 (6.3%)	-7.8 (6.3%)	-10.3 (7.8%)
$\Delta E_{\text{orb}(3)}^b$	cAAC-P \rightarrow Si(Cl)L π donation	-4.6 (3.5%)			-10.8 (8.2%)
	cAAC-P \leftarrow Si(Cl)L σ back donation		-7.4 (6.0%)	-6.8 (5.5%)	
$\Delta E_{\text{orb}(4)}^b$	cAAC-P \rightarrow Si(Cl)L σ donation	-8.8 (6.7%)	-3.9 (3.8%)	-4.0 (3.2%)	-5.0 (3.8%)
$\Delta E_{\text{orb}(\text{rest})}^b$		-4.7 (3.6%)	-4.9 (4.0%)	-5.2 (4.2%)	-5.2 (3.9%)

^a The values in the parentheses show the contribution to the total attractive interaction $\Delta E_{\text{elstat}} + \Delta E_{\text{orb}} + \Delta E_{\text{disp}}$. ^b The values in parentheses show the contribution to the total orbital interaction ΔE_{orb} .

endergonicity of dissociation in L-PSi(X) ($\Delta G^{298} = 42-68$ kcal mol⁻¹) is also higher than that of L-Si(X)P ($\Delta G^{298} = 27-59$ kcal mol⁻¹). The results indicate a higher thermodynamic

stability of the P-bonded species L-PSi(X) compared to the Si-bonded species L-Si(X)P. The low HOMO-LUMO energy gap ($\Delta_{\text{H-L}}$) of L-Si(X)P compounds (Tables S5 and S6†) can be

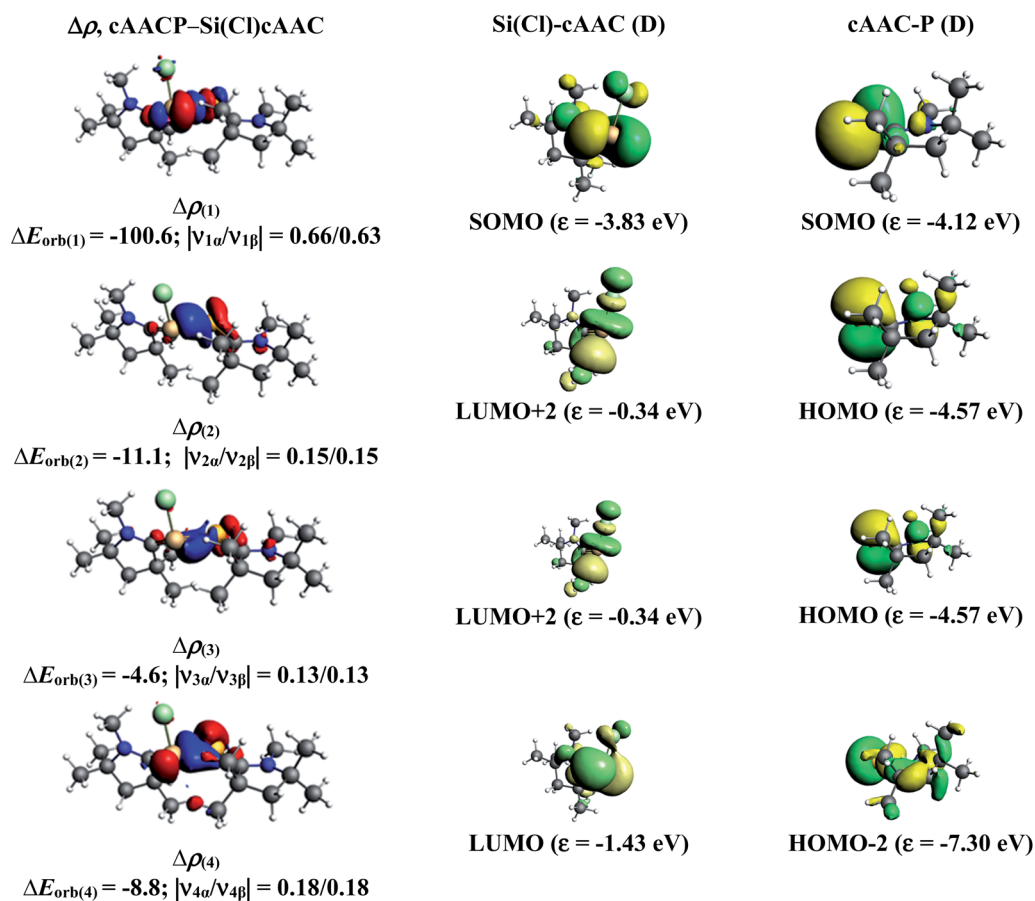


Fig. 6 The shape of the deformation densities, $\Delta\rho_{(1)-(4)}$ that correspond to $\Delta E_{\text{orb}(1)-(4)}$, and the associated MOs of cAAC-P-Si(Cl)-cAAC and the fragments orbitals of cAAC-P and (Cl)Si-cAAC in the doublet state at the BP86-D3(BJ)/TZ2P level. Isosurface values are 0.003 au for $\Delta\rho_{(1)-(3)}$ and isosurface value 0.0003 for $\Delta\rho_{(4)}$. The eigenvalues $|\nu_n|$ give the size of the charge migration in e. The direction of the charge flow of the deformation densities is red \rightarrow blue.

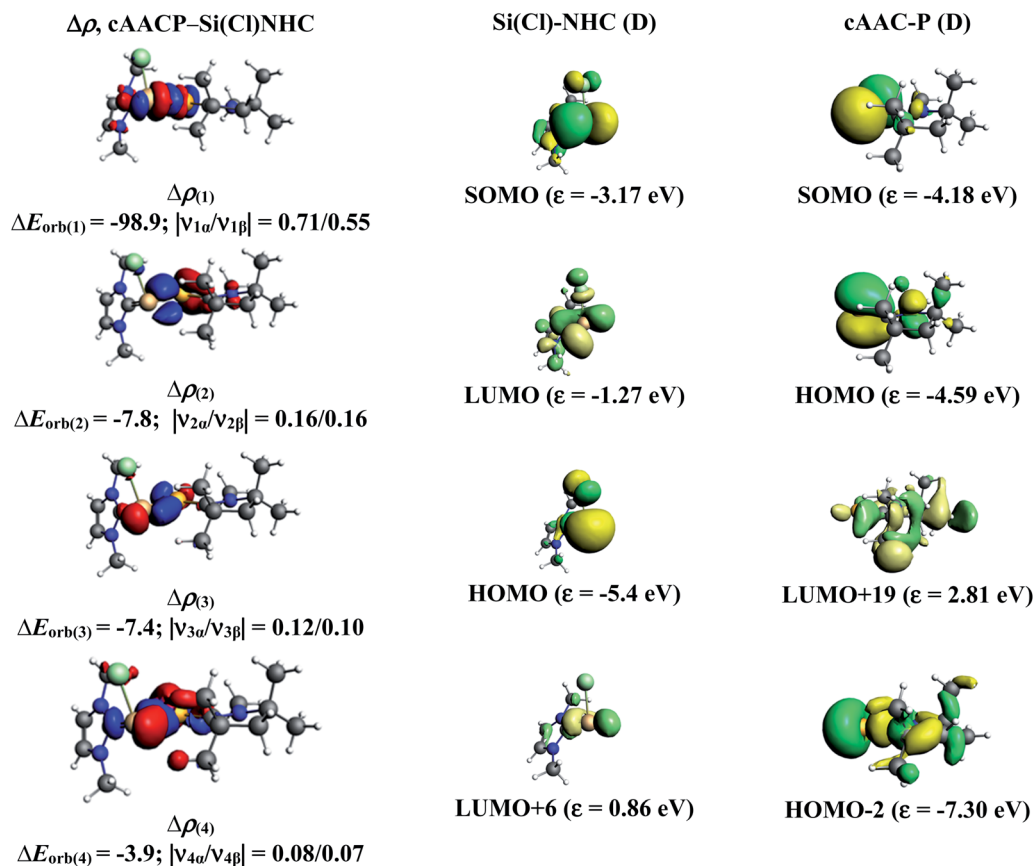


Fig. 7 The shape of the deformation densities, $\Delta\rho_{(1)-(4)}$ that correspond to $\Delta E_{orb(1)-(4)}$, and the associated MOs of cAAC-P-Si(Cl)-NHC and the fragments orbitals of cAAC-P and (Cl)Si-NHC in the doublet state at the BP86-D3(BJ)/TZ2P level. Isosurface values are 0.001 au for $\Delta\rho_{(1)-(3)}$ and isosurface value 0.0003 for $\Delta\rho_{(4)}$. The eigenvalues $|\nu_n|$ give the size of the charge migration in e. The direction of the charge flow of the deformation densities is red \rightarrow blue.

correlated with their low singlet-triplet energy gaps (ΔE_{S-T}) indicating that such species are electronically less stable and more reactive compared to L-PSi(X) and cAAC-PSi(X)-L compounds (L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC) (X = Cl, F).

The NBO analysis of L-PSi(X) and L-Si(X)P molecules (L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC) (X = Cl, F) shows the Wiberg bond indices (WBI) in the range of 1.1-1.34 for L-P bond and 1.22-1.42 for P-Si bond in L-PSi(X), indicating the double bond character for L-P and P-Si bonds, respectively (Tables S7-S10[†]). Whereas, in L-Si(X)P compounds the WBI values for L-Si and P-Si bonds are found in the range of 0.72 to 0.89 and 1.69-2.42, respectively indicating a single bond character for the L-Si bond and a weak triple bond character for the P-Si bond. The WBI values indicate higher bond order for the P-Si bond in L-Si(X)P when compared to that in L-PSi(X) and cAAC-PSi(X)-L molecules.

To understand the effect of ligand on the L-P and L-Si bonding, we have performed EDA-NOCV calculations on L-PSi(X) and P(X)Si-L (L = cAAC^{Me}, NHC^{Me}, PMe₃, aAAC; X = Cl, F). The calculations revealed (Tables S11-S14[†]) that except for cAAC-PSi(Cl) and aAAC-PSi(Cl), the nature of L-P bond is predominantly dative in nature. While, the L-P bond in cAAC-PSi(Cl) and aAAC-PSi(Cl) is a mixture of both dative and

electron sharing in nature with electron sharing σ bond and dative π backdonation from cAAC \leftarrow P. The L-P bond in fluorine substituted counterparts of L-PSi(X) molecules is found to be dative in nature, irrespective of the ligand field. Whereas, the L-Si bond in all P(X)Si-L compounds, except P(Cl)Si-aAAC is found to be dative in nature. The L-Si bond in P(Cl)Si-aAAC is found to be electron sharing covalent in nature. The instantaneous interaction energy (ΔE_{int}) of L-P bonds are higher compared to L-Si bond, but lower than that of the hetero ligand-stabilized cAAC-PSi(X)-L molecules. This indicates that the L-P bonds are stronger compared to the L-Si bonds of P(X)Si-L but weaker than that in cAAC-PSi(X)-L. The pairwise interactions (Fig. S17-S24[†]) of L-PSi(X) and P(X)Si-L (Tables S15 and S16[†]) show higher σ contribution (69.3-75.3%) and comparatively weak π contribution (8.5-20%). The π contribution of NHC and PMe₃ substituted species is less compared to cAAC substituted species. This can be attributed to the poor π accepting ability of NHC and PMe₃ ligands. The previous synthetic reports on NHC and cAAC stabilized Si=P-Ar (D-E)^{5,6} [Ar = Mes* or Tip] having bulky aryl group on P-atom, suggest the importance of steric bulk of the Ar-group to prevent the Si=P bond from further reacting with each other. The electronic and steric effects of the ligands are required in *n*-Cl/*n*-F compounds.

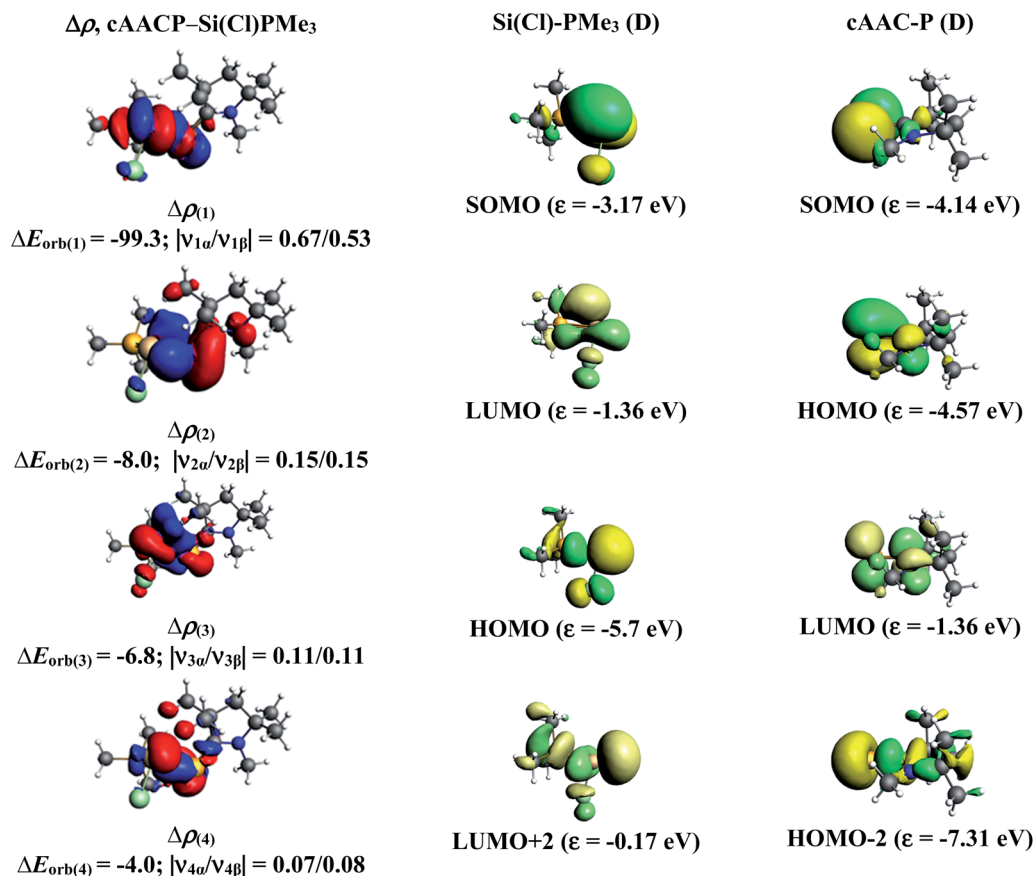


Fig. 8 The shape of the deformation densities, $\Delta\rho_{(1)-(4)}$ that correspond to $\Delta E_{\text{orb}(1)-(4)}$, and the associated MOs of cAAC–P–Si(Cl)–PMe₃ and the fragments orbitals of cAAC–P and (Cl)Si–PMe₃ in the doublet state at the BP86–D3(BJ)/TZ2P level. Isosurface values are 0.003 au. The eigenvalues $|v_r|$ give the size of the charge migration in e. The direction of the charge flow of the deformation densities is red → blue.

Conclusion

In conclusion, the quantum chemical calculations on four cAAC–PSi(Cl)–L (1-Cl to 4-Cl) and four cAAC–PSi(F)–L compounds (1-F to 4-F) with L = cAAC^{Me} (1-Cl, 1-F), NHC^{Me} (2-Cl, 2-F), PMe₃ (2-Cl, 2-F) and aAAC (4-Cl, 4-F) shows significant increase in C–P–Si–C torsion angle on changing the substitution on Si from chlorine (14.7° in 2-Cl) to fluorine (29.2° in 2-F) in cAAC–PSi(Cl/F)–NHC compounds. The EDA–NOCV calculations predict the best bonding scenario of cAAC–PSi(Cl)–L bonds in 1-Cl, 4-Cl and 1-F as both electron sharing and dative with singly charged interacting fragments [(cAAC)L]⁺ and [P–Si(Cl)][−] (Scheme 2; (4)). In 3-Cl and 3-F, the best bonding as σ and π electron sharing bonds and other σ and π dative bonds from the interaction of neutral [(cAAC)L] and P–Si(Cl/F) fragments in triplet electronic state (Scheme 2; (2)). While, in 2-Cl the best bonding can be described with singly charged interacting fragments [(cAAC)L]⁺ and [P–Si(Cl)][−] forming both electron sharing and dative bonds (Scheme 2; (4)). In contrast, the best bonding of 2-F comes from the interaction of neutral [(cAAC)L] and P–Si(Cl/F) fragments in triplet electronic states, forming σ - and π -electron sharing bonds and other σ - and π -dative bonds (Scheme 2; (2)). The bonding situation in 4-F can

be best described with two possibilities (Scheme 2; (4) and (5)); one, in terms of mixture of electron sharing and the other as dative bonds (4), as well as all electron sharing bonds (5). The HOMOs of cAAC/aAAC ligand are significantly higher in energy than those of NHC and PMe₃ ligands. This crucial difference makes L-containing (L = cAAC) complexes to possess different bonding in compounds 1-Cl, 4-Cl and 1-F, 4-F compared to other compounds. The P–Si bonding in all compounds can be best described by the interaction of neutral cAAC–P and Si(Cl/F)–L fragments in doublet state, forming electron sharing and dative bonds. The quantum chemical calculations and bonding analysis reveals that the single ligand-stabilized species, like L–PSi(Cl/F) and L–Si(Cl/F)P are less stable and reactive, hence, difficult to isolate. Finally, it can be stated that the reasonably high endergonic nature of dissociation, high singlet–triplet energy gaps and high HOMO–LUMO energy gaps supports the synthetic viability of hetero ligand-stabilized illusive PSi(Cl/F) species. The steric crowding of the ligands is also required to have the synthetic success of this class of molecules.

Conflicts of interest

Authors do not have any conflict of interest.

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